Absolute Maximum Ratings

Voltages Referenced to GND
V_{DD} .... −0.5V to +4.4V

V_{IN}, V_{COM}, V_{NC}, V_{NO} [1] ....−0.5V to V_+ +0.3V
or 30mA, whichever occurs first

Current (any terminal)... ±200mA

Peak Current, COM, NO, NC
(Pulsed at 1ms, 10% duty cycle)................................... ±400mA

Thermal Information

Continuous Power Dissipation
SOT23 (derate 7.1mW/ºC above +70ºC)............................ 0.5W

Storage Temperature ....−65ºC to +150ºC

Lead Temperature (soldering, 10s) .... +300ºC

Note 1: Signals on NC, NO, COM, or IN exceeding V_{DD} or GND are clamped by internal diodes. Limit forward diode current to 30mA.

Caution: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications - Single +4.2V Supply

(V_{DD} = +4.2V ± 5%, GND = 0V, V_{IH} = 1.6V, V_{IL} = 0.7V)

Parameter	Symbol	Conditions	Temp. (°C)	Min.[1]	Typ. [2]	Max. [1]	Units
Analog Switch							
Analog Signal Range [3]	V_{ANALOG}		Full	0		V_{DD}	V
On Resistance	R_{ON}	V_{DD} = 4.0V, I_{COM} = 99mA, V_{IN} = 0V to V_{DD}	25		0.4	0.45	Ω
			Full			0.6	
On-Resistance Match Between Channels[4]	ΔR_{ON}		25			0.08	
			Full			0.09	
On-Resistance Flatness[5]	$R_{FLAT(ON)}$	V_{DD} = 4.0V, I_{COM} = 100mA	25			0.1	
			Full			0.1	
NO or NC Off Leakage Current[6]	$I_{NO(OFF)}$ or $I_{NC(OFF)}$	V_{DD} =4.2V	25	-100		100	nA
			Full	-400		400	
COM On Leakage Current[6]	$I_{COM(ON)}$	V_{DD} = 4.2V	25	-200		200	
			Full	-400		400	

Notes:
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design.
4. ΔR_{ON} = R_{ON} max. - R_{ON} min.
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25ºC.
7. Off Isolation = 20log$_{10}$ [V_{COM} / (V_{NO} or V_{NC})]. See Figure 4.
8. Between any two switches. See Figure 5.

Electrical Specifications - Single +3.3V Supply

(V_{DD} = +3.3V ± 10%, GND = 0V, V_{IH} = 1.4V, V_{IL} = 0.5V)

Parameter	Symbol	Conditions	Temp. (°C)	Min.[1]	Typ. [2]	Max. [1]	Units
Analog Switch							
Analog Signal Range [3]	V_{ANALOG}		Full	0		V_{DD}	V
On Resistance	R_{ON}	V_{DD} = 2.7V, I_{COM} = 100mA, V_{NO} or V_{NC} = +1.5V	25		0.4	0.45	Ω
			Full			0.6	
On-Resistance Match Between Channels[4]	ΔR_{ON}		25			0.08	
			Full			0.09	
On-Resistance Flatness[5]	$R_{FLAT(ON)}$	V_{DD} = 2.7V, I_{COM} = 100mA, V_{NO} or V_{NC} = 0.8V, 2.0V	25			0.1	
			Full			0.1	
NO or NC Off Leakage Current[6]	$I_{NO(OFF)}$ or $I_{NC(OFF)}$	V_{DD} = 3.3V, V_{COM} = 0V, V_{NO} or V_{NC} = +2.0V	25	-100		100	nA
			Full	-400		400	
COM On Leakage Current[6]	$I_{COM(ON)}$	V_{DD} = 3.3V, V_{COM} = +2.0V, V_{NO} or V_{NC} = +2.0V	25	-200		200	
			Full	-400		400	

Notes:
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design.
4. ΔR_{ON} = R_{ON} max. - R_{ON} min.
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25ºC.
7. Off Isolation = $20\log_{10}$ [V_{COM} / (V_{NO} or V_{NC})]. See Figure 4.
8. Between any two switches. See Figure 5.

Electrical Specifications - Single +4.2V Supply

(V_{DD} = +4.2V ± 5%, GND = 0V, V_{IH} = 1.6V, V_{IL} = 0.7V)

Description	Parameters	Test Conditions	Temp (ºC)	Min.[1]	Typ.[2]	Max.[1]	Units
Logic Input							
Input High Voltage	V_{IH}	Guaranteed logic High Level	Full	1.6			V
Input Low Voltage	V_{IL}	Guaranteed logic Low Level				0.7	
Input Current with Voltage High	I_{INH}	V_{IN} = 1.4V, all others = 0.5V		–1		1	µA
Input Current with Voltage Low	I_{INL}	V_{IN} = 0.5V, all other = 1.4V		–1		1	
Dynamic							
Turn-On Time	t_{ON}	V_{DD} = 4.2V, V_{NO} or V_{NC} = 2.0V, Figure 1	25			20	ns
			Full			25	
Turn-Off Time	t_{OFF}		25			12	
			Full			15	
Break-Before-Make	t_{BBM}	V_{NO} or V_{NC} = 1.5V, R_L = 50Ω, C_L = 35pF, See Figure 8	25	1	12		
			Full	1			
Charge Injection[3]	Q	C_L = 1nF, V_{GEN} = 0V, R_{GEN} = 0Ω, Figure 2	25		100		pC
Off Isolation[7]	O_{IRR}	R_L = 50Ω, f = 100kHz, Figure 3			-27		dB
Cross Talk[8]	X_{TALK}	R_L = 50Ω, f = 100kHz, Figure 4			-41		
NC or NO Capacitance	$C_{(OFF)}$	f = 1MHz, Figure 5			56		pF
COM Off Capacitance	$C_{COM(OFF)}$				56		
COM On Capacitance	$C_{COM(ON)}$	f = 1MHz, Figure 6			160		
Supply							
Power-Supply Range	V_{DD}		Full	1.5		3.6	V
Positve Supply Current	I_{CC}	V_{DD} = 3.6V, V_{IN} = 0V or V_{DD}	25			0.3	µA

Notes:
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design.
4. ΔR_{ON} = R_{ON} max. - R_{ON} min.
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25ºC.
7. Off Isolation = $20\log_{10}$ [V_{COM} / (V_{NO} or V_{NC})]. See Figure 4.
8. Between any two switches. See Figure 5.

Electrical Specifications - Single +3.3V Supply

(V_{DD} = +3.3V ± 10%, GND = 0V, V_{IH} = 1.4V, V_{IL} = 0.5V)

Description	Parameters	Test Conditions	Temp (ºC)	Min.[1]	Typ.[2]	Max.[1]	Units
Logic Input							
Input High Voltage	V_{IH}	Guaranteed logic High Level	Full	1.4			V
Input Low Voltage	V_{IL}	Guaranteed logic Low Level				0.5	
Input Current with Voltage High	I_{INH}	V_{IN} = 1.4V, all others = 0.5V		–1		1	μA
Input Current with Voltage Low	I_{INL}	V_{IN} = 0.5V, all other = 1.4V		–1		1	
Dynamic							
Turn-On Time	t_{ON}	V_{DD} = 3.3V, V_{NO} or V_{NC} = 2.0V, Figure 1	25			20	ns
			Full			25	
Turn-Off Time	t_{OFF}		25			12	
			Full			15	
Break-Before-Make	t_{BBM}	V_{NO} or V_{NC} = 1.5V, R_L = 50Ω, C_L = 35pF, See Figure 8	25	1	12		
			Full	1			
Charge Injection[3]	Q	C_L = 1nF, V_{GEN} = 0V, R_{GEN} = 0Ω, Figure 2	25		100		pC
Off Isolation[7]	O_{IRR}	R_L = 50Ω, f = 100kHz, Figure 3			-27		dB
Cross Talk[8]	X_{TALK}	R_L = 50Ω, f = 100kHz, Figure 4			-41		
NC or NO Capacitance	$C_{(OFF)}$	f = 1MHz, Figure 5			56		pF
COM Off Capacitance	$C_{COM(OFF)}$				56		
COM On Capacitance	$C_{COM(ON)}$	f = 1MHz, Figure 6			160		
Supply							
Power-Supply Range	V_{DD}		Full	1.5		3.6	V
Positve Supply Current	I_{CC}	V_{DD} = 3.6V, V_{IN} = 0V or V_{DD}	25			0.3	μA

Notes:
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design.
4. ΔR_{ON} = R_{ON} max. - R_{ON} min.
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25ºC.
7. Off Isolation = $20\log_{10}$ [V_{COM} / (V_{NO} or V_{NC})]. See Figure 4.
8. Between any two switches. See Figure 5.

Electrical Specifications - Single +1.8V Supply

(V_{DD} = +1.8V ± 10%, GND = 0V, V_{INH} = 1.4V, V_{INL} = 0.5V)

Description	Parameters	Test Conditions	Temp.(°C)	Min.[1]	Typ.[2]	Max.[1]	Units
Analog Switch							
Analog Signal Range[3]	V_{ANALOG}			0		V_{DD}	V
On-Resistance	R_{ON}	V_{DD} = 1.8V, I_{COM} = 60mA, V_{NO} or V_{NC} = 1.5V	25			0.55	Ω
			Full			0.7	
On-Resistance Match Between Channels [4]	ΔR_{ON}		25			0.03	
			Full			0.03	
On-Resistance Flatness[5]	$R_{FLAT(ON)}$	V_{DD} = 1.8V, I_{COM} = 60mA, V_{NO} or V_{NC} = 0.8V, 1.5V	25			0.9	
			Full			1.1	
Dynamic							
Turn-On Time	t_{ON}	V_{DD} = 1.8V, V_{NO} or V_{NC} = 1.5V, Figure 1	25			40	ns
			Full			50	
Turn-Off Time	t_{OFF}		25			12	
			Full			15	
Break-Before-Make	t_{BBM}	V_{NO} or V_{NC} = 1.5V, R_L = 50Ω, C_L = 35pF, See Figure 8	25	1	30		
Charge Injection[3]	Q	C_L = 1nF, V_{GEN} = 0V, R_{GEN} = 0V, Figure 2	25		40		pC
Logic Input							
Input HIGH Voltage	V_{IH}	Guaranteed logic high level	Full	1.4			V
Input LOW Voltage	V_{IL}	Guaranteed logic Low level	Full			0.5	
Input HIGH Current	I_{INH}	V_{IN} = 1.4V, all others = 0.5V	Full	−1		1	μA
Input HIGH Current	I_{INL}	V_{IN} = 0.5V, all others =1.4V	Full	−1		1	

Notes:
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design.
4. ΔR_{ON} = R_{ON} max. - R_{ON} min.
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
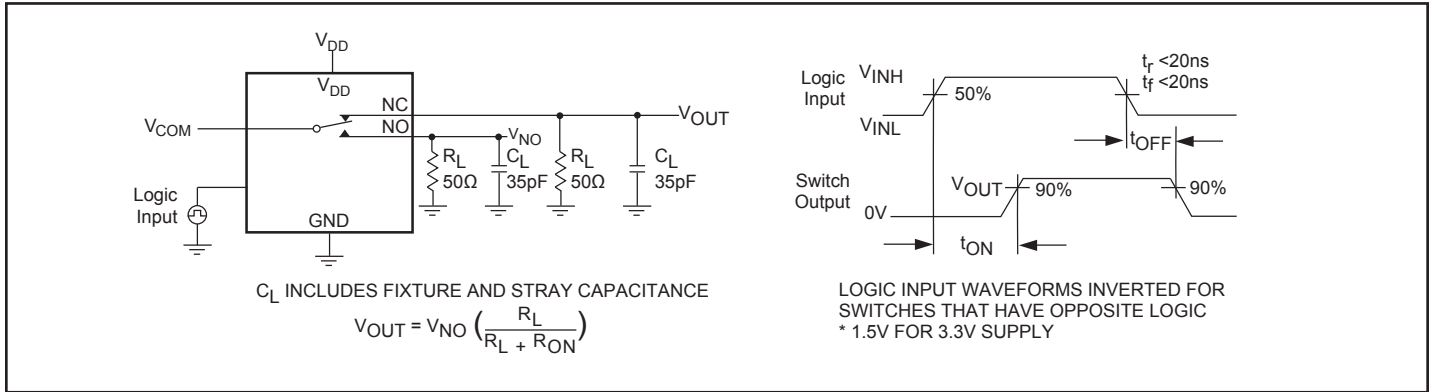
Test Circuits/Timing Diagrams

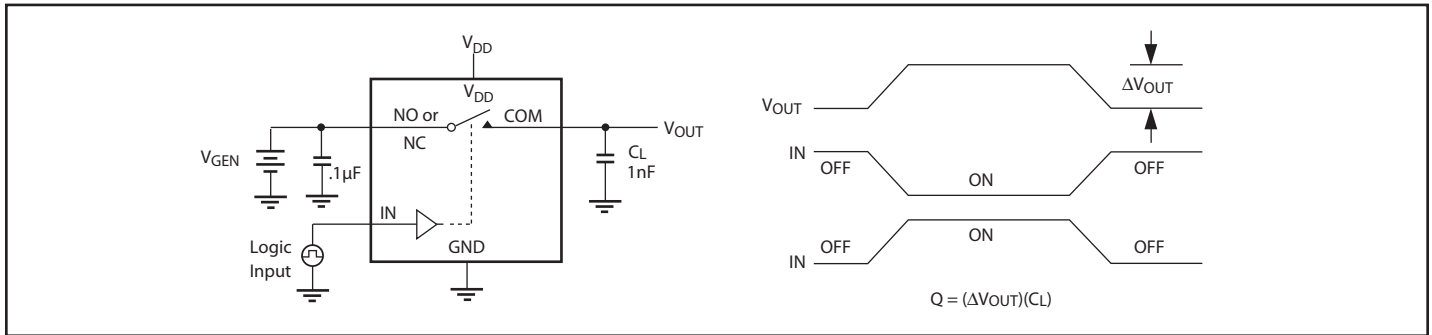C_L INCLUDES FIXTURE AND STRAY CAPACITANCE

$$V_{OUT} = V_{NO}\left(\frac{R_L}{R_L + R_{ON}}\right)$$

LOGIC INPUT WAVEFORMS INVERTED FOR
SWITCHES THAT HAVE OPPOSITE LOGIC
* 1.5V FOR 3.3V SUPPLY

Figure 1. Switching Time

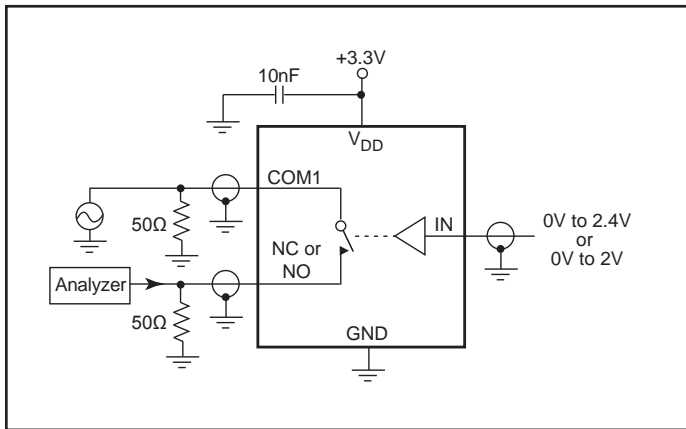$Q = (\Delta V_{OUT})(C_L)$

Figure 2. Charge Injection
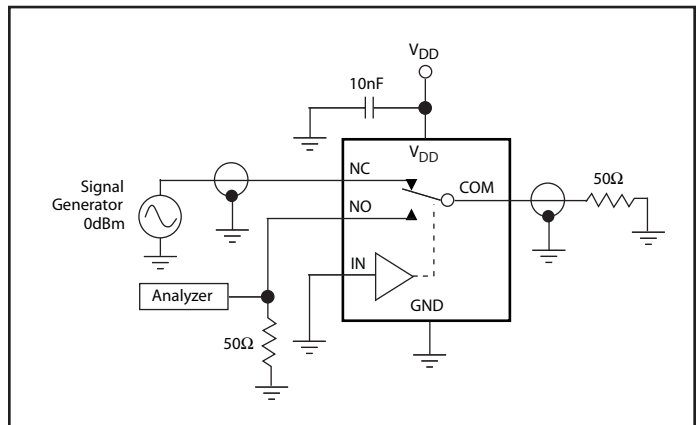

Figure 3. Off Isolation

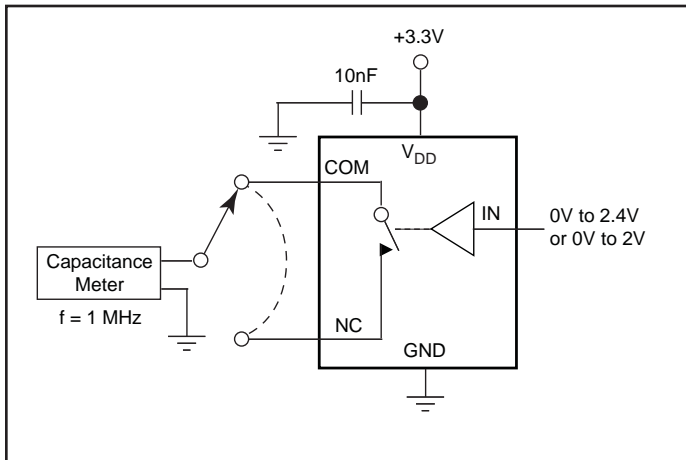**Figure 4. Crosstalk**

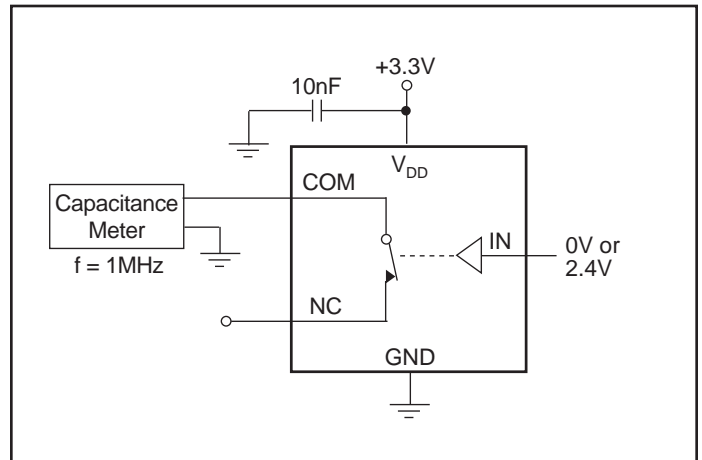## Test Circuits/Timing Diagrams (continued)

Figure 5. Channel-Off Capacitance

Figure 6. Channel-On Capacitance

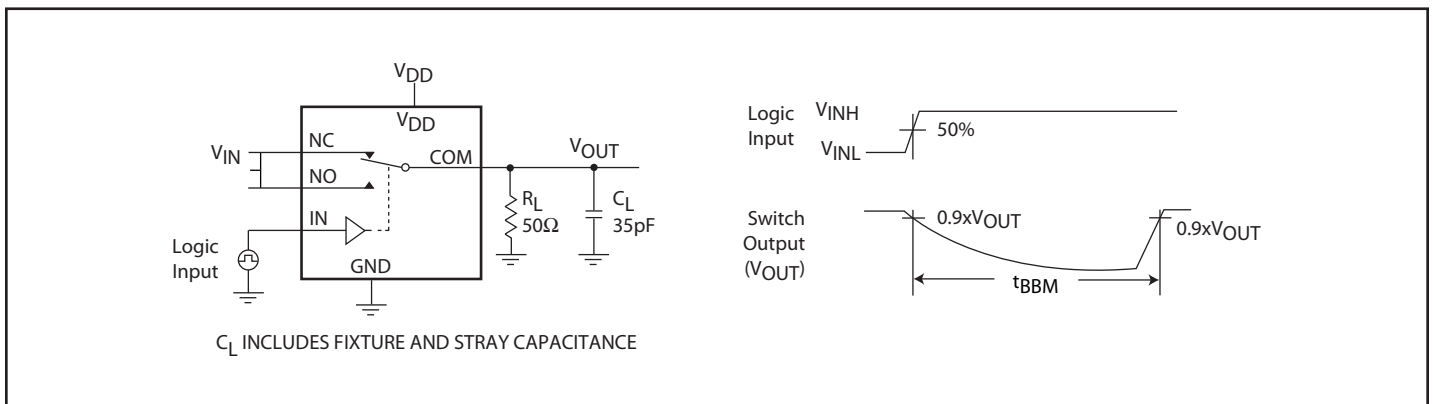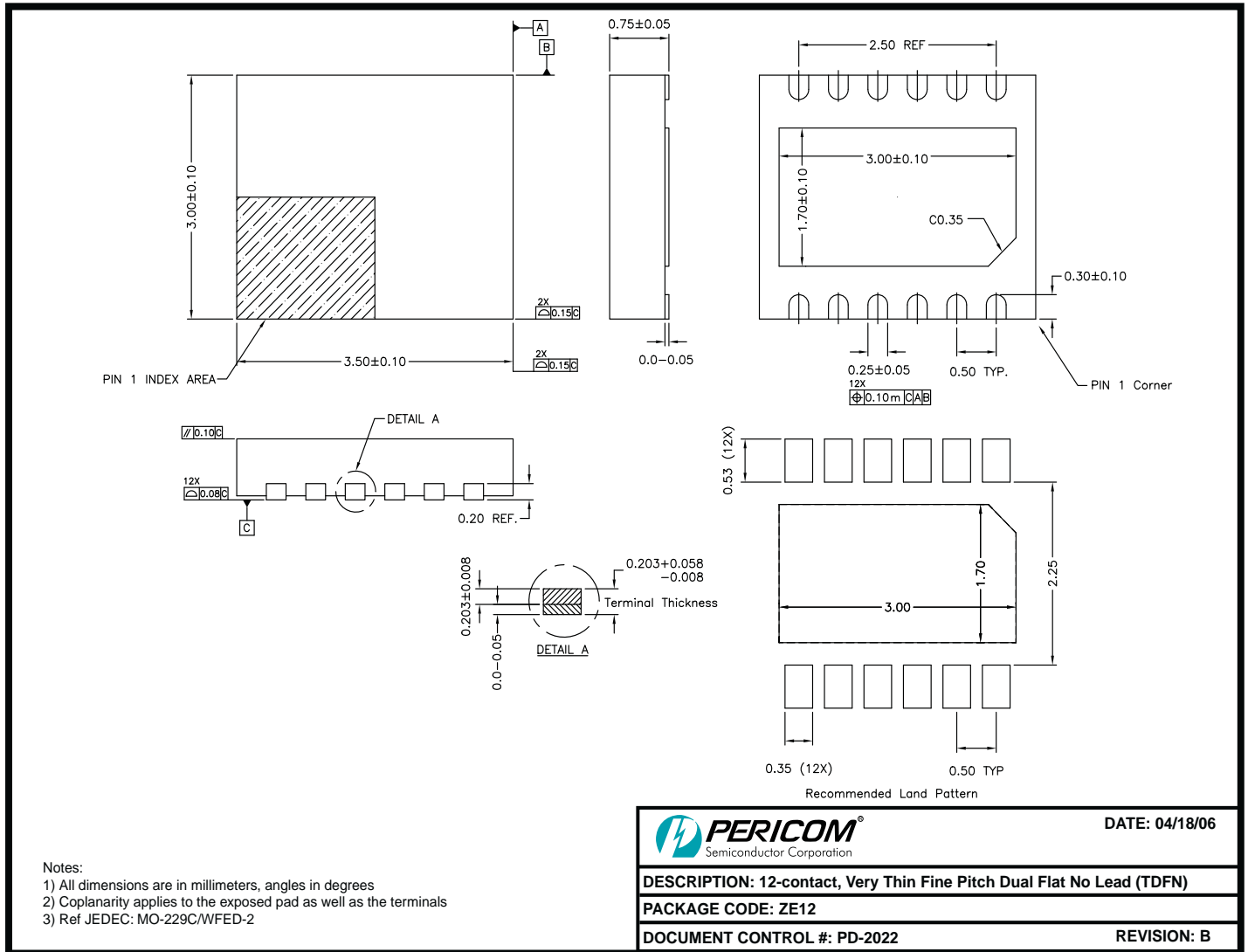C_L INCLUDES FIXTURE AND STRAY CAPACITANCE

Figure 8. Break Before Make Diagram

Packaging Mechanical: 12-Contact TDFN (ZE)

Notes:
1) All dimensions are in millimeters, angles in degrees
2) Coplanarity applies to the exposed pad as well as the terminals
3) Ref JEDEC: MO-229C/WFED-2

DATE: 04/18/06

DESCRIPTION: 12-contact, Very Thin Fine Pitch Dual Flat No Lead (TDFN)

PACKAGE CODE: ZE12

DOCUMENT CONTROL #: PD-2022   **REVISION: B**

06-0360

Note:
• For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

Ordering Information

Ordering Code	Package Code	Package Description	Top Mark
PI3A3160ZEEX	ZE	Pb-free & Green, 12-contact TDFN	YI

Notes:
1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
2. X = Tape/Reel
3. Number of transistors = TBD

Mouser Electronics

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